



**THE DATASHEET OF  
NSVBAS21HT3G**



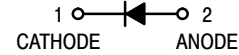
# High Voltage Switching Diode

## HIGH VOLTAGE SWITCHING DIODE

### BAS21H

#### Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



#### MAXIMUM RATINGS

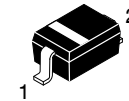
Rating	Symbol	Value	Unit
Continuous Reverse Voltage	$V_R$	250	V
Repetitive Peak Reverse Voltage	$V_{RRM}$	250	V
Peak Forward Current	$I_F$	200	mA
Repetitive Peak Forward Current	$I_{FRM}$	500	mA
Non-Repetitive Peak Forward Surge Current, 60 Hz	$I_{FSM(surge)}$	2.5	A
Non-Repetitive Peak Forward Current (Square Wave, $T_J = 25^\circ\text{C}$ prior to surge)	$I_{FSM}$		A
$t = 1 \mu\text{s}$		20	
$t = 10 \mu\text{s}$		20	
$t = 100 \mu\text{s}$		10	
$t = 1 \text{ ms}$		4	
$t = 1 \text{ s}$		1	

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	200	mW
		1.57	mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient Junction-to-Lead Junction-to-Top	$R_{\theta JA}$ $R_{\theta JL}$ $R_{\theta JT}$	635 240 436	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-5 Minimum Pad



SOD-323  
CASE 477  
STYLE 1

#### MARKING DIAGRAM



JS = Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

Device	Package	Shipping†
BAS21HT1G, NSVBAS21HT1G	SOD-323 (Pb-Free)	3000 / Tape & Reel
BAS21HT3G, NSVBAS21HT3G	SOD-323 (Pb-Free)	10000 / Tape & Reel

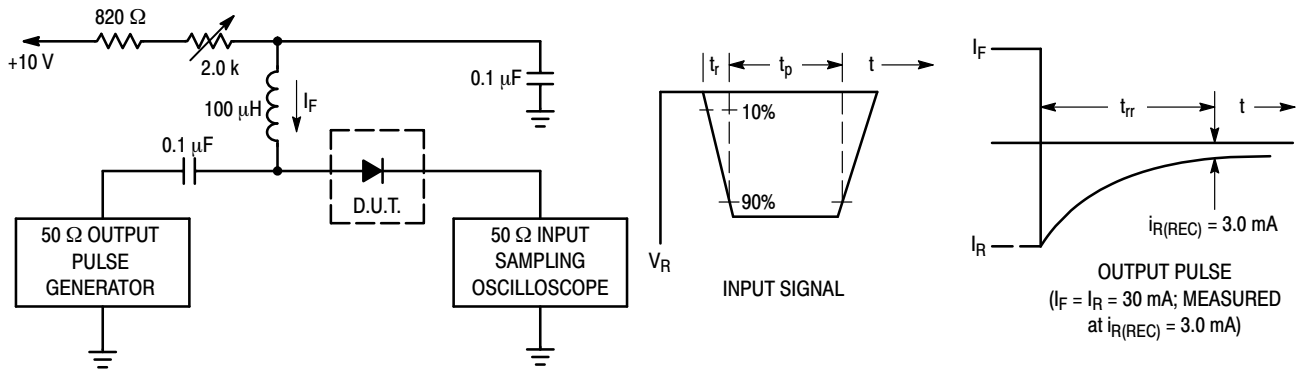
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Reverse Voltage Leakage Current ( $V_R = 200 \text{ Vdc}$ ) ( $V_R = 200 \text{ Vdc}$ , $T_J = 150^\circ\text{C}$ )	$I_R$	-	0.1 100	$\mu\text{A}$ $\text{dc}$
Reverse Breakdown Voltage ( $I_{BR} = 100 \mu\text{A}$ )	$V_{(BR)}$	250	-	Vdc
Forward Voltage ( $I_F = 100 \text{ mA}$ ) ( $I_F = 200 \text{ mA}$ )	$V_F$	-	1000 1250	mV
Diode Capacitance ( $V_R = 0$ , $f = 1.0 \text{ MHz}$ )	$C_D$	-	5.0	pF
Reverse Recovery Time ( $I_F = I_R = 30 \text{ mA}$ , $R_L = 100 \Omega$ )	$t_{rr}$	-	50	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



- Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current ( $I_F$ ) of 30 mA.  
 2. Input pulse is adjusted so  $I_{R(\text{peak})}$  is equal to 30 mA.  
 3.  $t_p \gg t_{rr}$

**Figure 1. Recovery Time Equivalent Test Circuit**

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## TYPICAL CHARACTERISTICS

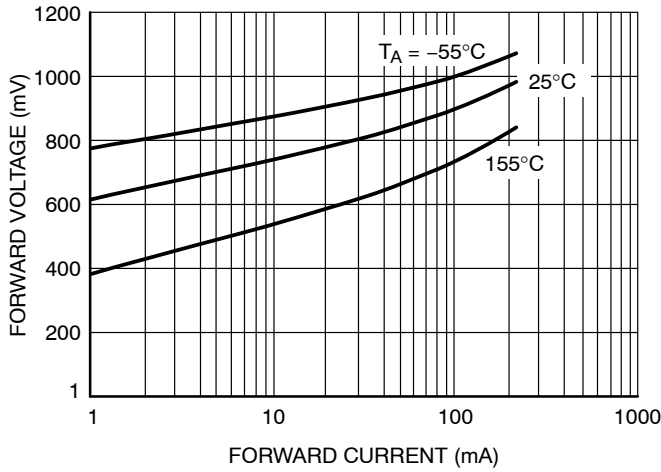


Figure 2. Forward Voltage

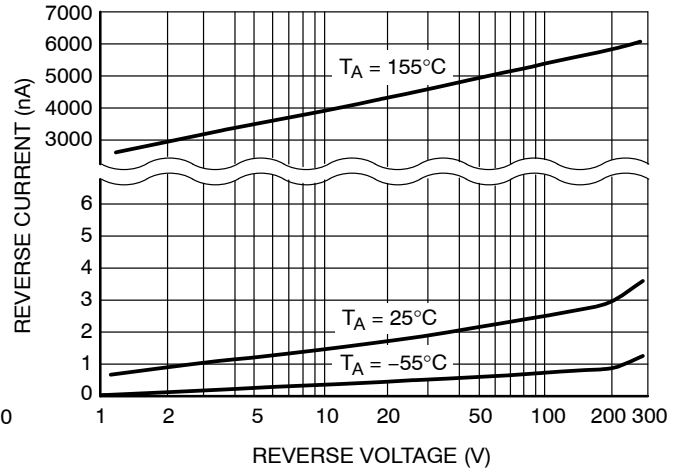


Figure 3. Reverse Leakage

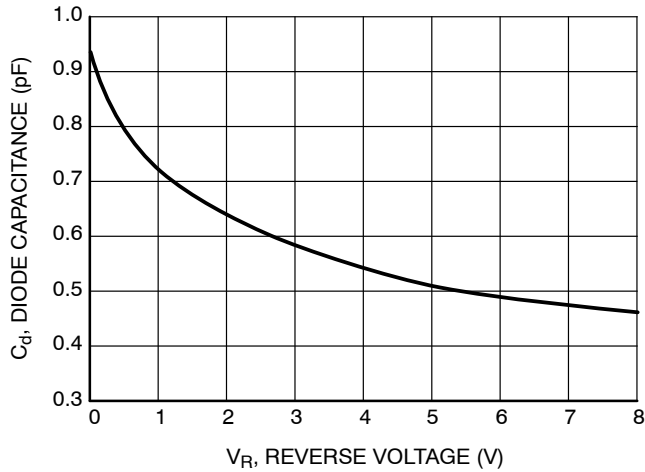


Figure 4. Diode Capacitance

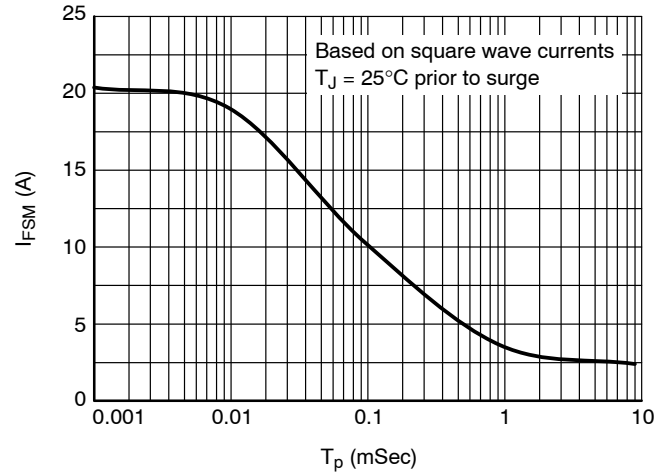
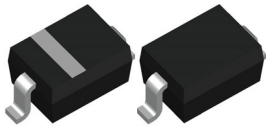


Figure 5. Maximum Non-repetitive Peak Forward Current as a Function of Pulse Duration, Typical Values

# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS



**SOD-323 1.70x1.25x0.85**  
**CASE 477**  
**ISSUE K**

DATE 11 MAR 2024



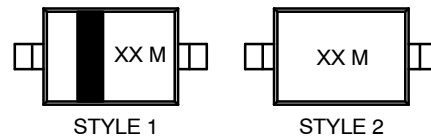
NOTES:

1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
5. DIMENSION L IS MEASURE FROM END OF RADIUS.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.80	0.90	1.00
A1	0.00	0.05	0.10
A2	0.75	0.85	0.95
A3	0.15 (REF)		
b	0.25	0.32	0.4
c	0.09	0.12	0.18
D	1.60	1.70	1.80
E	1.15	1.25	1.35
H	2.30	2.50	2.70
L	0.08	---	---
L1	0.40 (REF)		

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference manual, SOLDERRM/D.

### GENERIC MARKING DIAGRAM\*



XX = Specific Device Code  
M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: PIN 1. CATHODE (POLARITY BAND)  
2. ANODE

STYLE 2: NO POLARITY

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<b>DESCRIPTION:</b>	<b>SOD-323 1.70x1.25x0.85</b>	<b>PAGE 1 OF 1</b>

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